

EPO-TEK® H20S

Technical Data Sheet For Reference Only

Electrically Conductive, Silver Epoxy for Die Stamping

Date: September 2017

Rev: XI No. of Components: Two

Mix Ratio by Weight: 1:1

Specific Gravity: Part A: 1 **Pot Life:** 3 Days

Part A: 1.74 Part B: 3.07

3 Days

Shelf Life- Bulk: One year at room temperature

Recommended Cure: 150°C / 1 Hour

Minimum Alternative Cure(s):

May not achieve performance properties listed below

150°C / 5 Minutes 120°C / 15 Minutes 100°C / 45 Minutes 80°C / 90 Minutes

NOTES:

• Container(s) should be kept closed when not in use.

• Filled systems should be stirred thoroughly before mixing and prior to use.

• Performance properties (rheology, conductivity, others) of the product may vary from those stated on the data sheet when bi-pak/syringe packaging or post-processing of any kind is performed. Epoxy's warranties shall not apply to any products that have been reprocessed or repackaged from Epoxy's delivered status/container into any other containers of any kind, including but not limited to syringes, bi-paks, cartridges, pouches, tubes, capsules, films or other packages.

<u>Product Description:</u> EPO-TEK® H20S is a modified version of EPO-TEK® H20E, designed primarily for die stamping and dispensing techniques for chip bonding. EPO-TEK® H20S is a highly reliable, two component, silver-filled epoxy with a smooth, thixotropic consistency. In addition to the high electrical conductivity, the short curing cycles, the proven reliability, and the convenient mix ratio, EPO-TEK® H20S is extremely simple to use.

<u>Typical Properties:</u> Cure condition: 150°C / 1 Hour Different batches, conditions & applications yield differing results.

Data below is not guaranteed. To be used as a guide only, not as a specification. * denotes test on lot acceptance basis

PHYSICAL PROPERTIES:			
* Color (before cure):	Part A:	Silver Pa	rt B: Silver
* Consistency:	Smooth	thixotropic pa	aste
* Viscosity (23°C) @ 100 rpm:	1	1,800 - 2,800	cPs
Thixotropic Index:		5.0	
* Glass Transition Temp:		≥ 80	°C (Dynamic Cure: 20-200°C/ISO 25 Min; Ramp -10-200°C @20°C/Min)
Coefficient of Thermal Expansion (CTI	≣):		
Below	Гg:	31	x 10 ⁻⁶ in/in°C
Above	Гg:	120	x 10 ⁻⁶ in/in°C
Shore D Hardness:		64	
Lap Shear @ 23°C:		1,240	psi
Die Shear @ 23°C:		≥ 5	Kg 1,778 psi
Degradation Temp:		414	°C
Weight Loss:			
@ 200	_	0.40	%
@ 250	-	0.60	%
@ 300	°C:	1.37	%
Suggested Operating Temperature:		< 300	°C (Intermittent)
Storage Modulus:		339,720	psi
Ion Content:	Cl⁻:	162 ppm	Na ⁺ : 0 ppm
	NH ₄ +:	282 ppm	K+: 4 ppm
* Particle Size:		≤ 20	microns

ELECTRICAL AND THERMAL PROPERTIES:		
Thermal Conductivity:	3.3	W/mK
* Volume Resistivity @ 23°C:	≤ 0.0005	Ohm-cm



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EPO-TEK® H20S Advantages & Suggested Application Notes:

- Especially recommended for use in high speed epoxy chip bonding systems where fast cures are highly desirable.
- Suggested for JEDEC Level III and II plastic IC packaging.
- The low temperature cure makes it ideal for flex circuitry and other low stress applications.
- It is used extensively for bonding quartz crystal oscillators and other stress sensitive chips.
- Used for die and SMD bonding inside hybrid/hermetic packages such as DIP and TO-Cans; also EMI/Rf shielding of micro-electronics.
- Ideal for making ITO electrical contacts in LCD packaging; and suggested for LED dieattach.